Maximum Ratings

Т	. =	25	$^{\circ}C$

Parameter	Symbol		Values
Operating temperature	T _{op}	min.	-40 °C
	ор	max.	125 °C
Storage temperature	T _{stg}	min.	-40 °C
	Sig	max.	125 °C
Junction temperature	T _i	max.	145 °C
Forward current	I _F	max.	1000 mA
Surge current $t_0 \le 200 \ \mu s; D = 0$	I _{FSM}	max.	5 A
Reverse current ²⁾	l _R	max.	200 mA
Power consumption	P _{tot}	max.	3400 mW
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V _{ESD}	max.	2 kV



Characteristics

 $I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}; T_A = 25 \text{ °C}$

Parameter	Symbol		Values
Peak wavelength	λ_{peak}	typ.	860 nm
Centroid wavelength	$\lambda_{ ext{centroid}}$	typ.	850 nm
Spectral bandwidth at 50% I _{rel,max} (FWHM)	Δλ	typ.	30 nm
Half angle	φ	typ.	60 °
Dimensions of active chip area	LxW	typ.	1 x 1 mm x mm
Rise time (10% / 90%) $I_F = 5 \text{ A}; R_L = 50 \Omega$	t _r	typ.	7 ns
Fall time (10% / 90%) $I_F = 5 \text{ A}; R_L = 50 \Omega$	t _f	typ.	14 ns
Forward voltage $I_F = 1 \text{ A}; t_p = 100 \mu\text{s}$	V _F	typ. max.	3 V 3.4 V
Forward voltage $I_F = 5 \text{ A}; t_p = 100 \mu\text{s}$	V _F	typ. max.	3.5 V 4.5 V
Reverse voltage ²⁾ I _R = 20 mA	V_R	max.	1.2 V
Reverse voltage (ESD device) 2)	V_{RESD}	min.	45 V
Radiant intensity $^{3)}$ I _F = 1 A; t _p = 100 µs	l _e	typ.	320 mW/sr
Temperature coefficient of voltage	TC_v	typ.	-2 mV / K
Temperature coefficient of brightness	TC _I	typ.	-0.3 % / K
Temperature coefficient of wavelength	TC _λ	typ.	0.3 nm / K
Thermal resistance junction solder point real 4)	R_{thJS}	max.	9.0 K / W

Brightness Groups

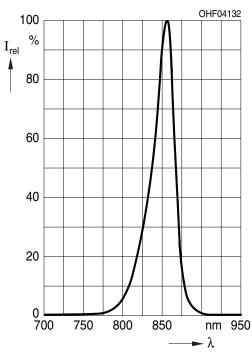
T_A = 25 °C

Group	Total radiant flux $^{1)}$ $I_F = 1000$ mA; $t_p = 10$ ms min. Φ_e	Total radiant flux $^{1)}$ $I_F = 1000$ mA; $t_p = 10$ ms max. Φ_e
EA	630 mW	1000 mW
EB	800 mW	1250 mW

Only one group in one packing unit (variation lower 1.6:1).

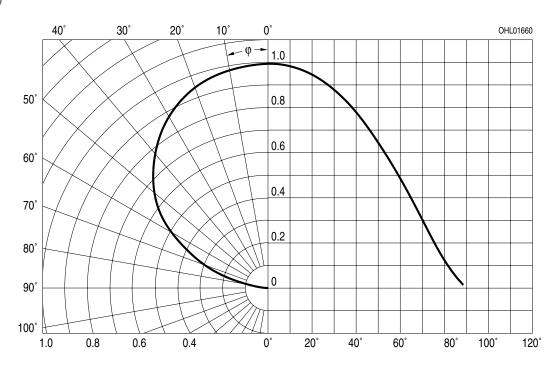
Relative Spectral Emission 5), 6)

 $I_{e,rel} = f(\lambda); I_F = 1000 \text{ mA}; t_p = 10 \text{ ms}$



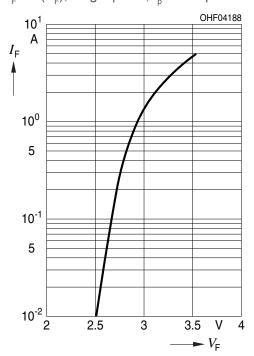
Radiation Characteristics 5), 6)

$$I_{e,rel} = f(\phi)$$



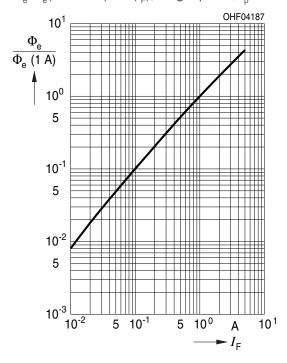
Forward current 5), 6)

 $I_F = f(V_F)$; single pulse; $t_D = 100 \mu s$



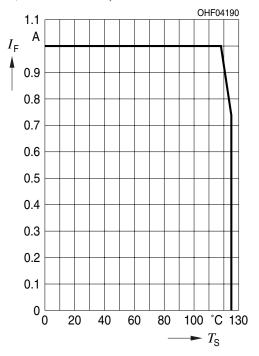
Relative Total Radiant Flux 5), 6)

 $\Phi_{\rm e}/\Phi_{\rm e}(1000{\rm mA})$ = f (I_F); single pulse; t_p = 100 $\mu {\rm s}$



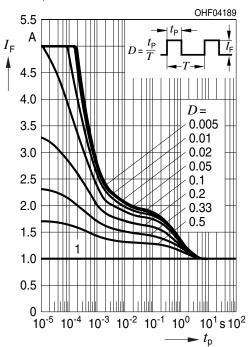
Max. Permissible Forward Current

$$I_{F,max} = f(T_S); Rth_{js} = 9K / Wsingle pulse$$

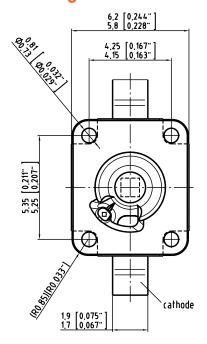


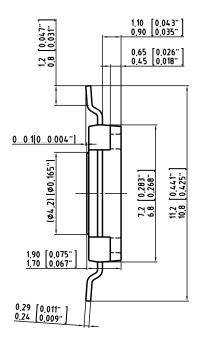
Permissible Pulse Handling Capability

 $I_F = f(t_p)$; duty cycle D = parameter; $T_S = 85^{\circ}C$



Dimensional Drawing 7)





C67062-A0007-A2-02

Further Information

Approximate Weight: 219.0 mg

Package marking: Cathode

Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

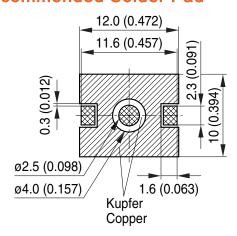
60068-2-43)

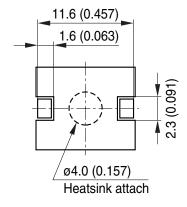
ESD advice: The device is protected by ESD device which is connected in parallel to the

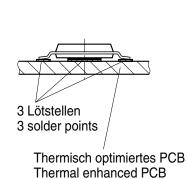
Chip.



Recommended Solder Pad 7)







Lötstopplack Solder resist

Lötpasten Schablone Solder paste stencil

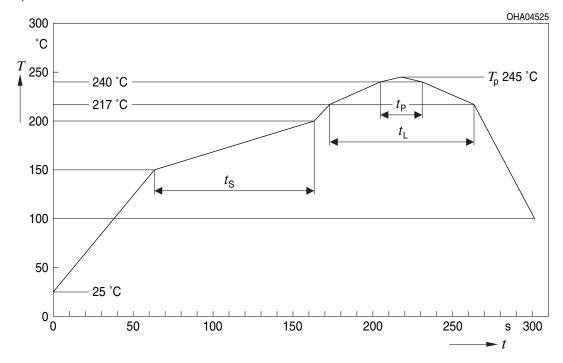
Bare Copper Freies Kupfer

OHAY0681

Anode and heatsink are electrically connected.

Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



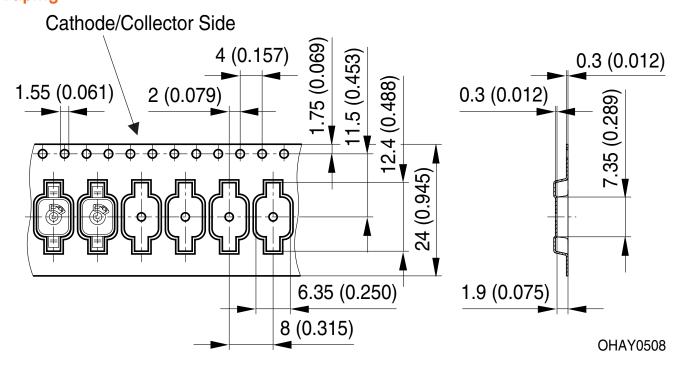
Profile Feature	Symbol	Pb	-Free (SnAgCu) Ass	sembly	Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t _s	t_s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak	t _P	10	20	30	S
temperature T _P - 5 K					
Ramp-down rate*			3	6	K/s
T _P to 100 °C					
Time				480	S
25 °C to T _P					

All temperatures refer to the center of the package, measured on the top of the component



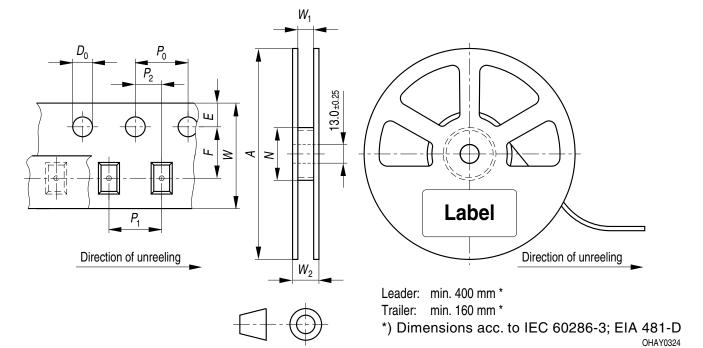
^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 7)





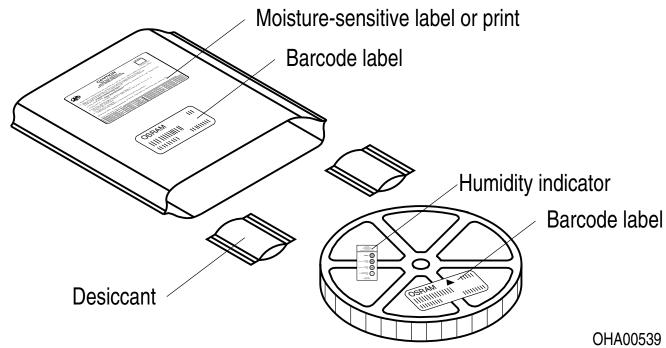
Tape and Reel 8)



Reel Dimensions

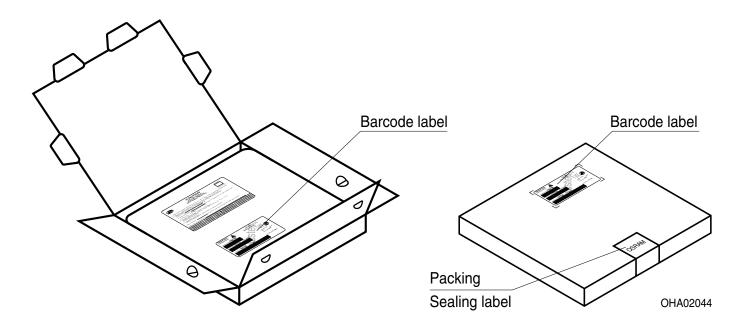
Α	W	N_{\min}	W ₁	$W_{2 \text{ max}}$	Pieces per PU
180 mm	24 + 0.3 / - 0.1 mm	60/100 mm	24.4 + 2 mm	30.4 mm	800

Dry Packing Process and Materials 7)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

Schematic Transportation Box 7)



Dimensions of Transportation Box

Width	Length	Height
195 ± 5 mm	195 ± 5 mm	42 ± 5 mm

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes

Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- 1) **Total radiant flux:** Measured with integrating sphere.
- Reverse Operation: Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- Radiant intensity: Measured at a solid angle of Ω = 0.01 sr
- Thermal resistance: junction soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁶⁾ **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ⁸⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision	n History	
Version	Date	Change
1.6	2019-07-15	Discontinued



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